EMH15 / IMH15A

NPN 100mA 50V Complex Digital Transistors (Bias Resistor Built-in Transistors)

Datasheet

Parameter	Tr1 and Tr2
V_{CEO}	50V
I _{C(MAX.)}	100mA
R_1	47kΩ

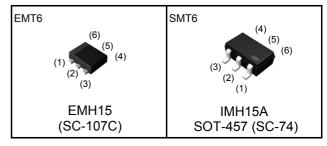
Features

- 1) Built-In Biasing Resistors.
- 2) Two DTC144T chips in one package.
- 3) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 4) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 5) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 6) Lead Free/RoHS Compliant.

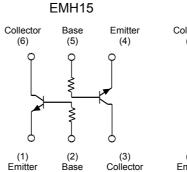
Application

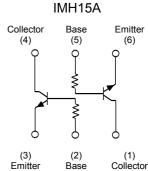
Inverter circuit, Interface circuit, Driver circuit

Outline



•Inner circuit





Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMH15	EMT6	1616	T2R	180	8	8,000	H15
IMH15A	SMT6	2928	T108	180	8	3,000	H15

● Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter		Symbol	Values	Unit
Collector-base voltage		V _{CBO}	50	V
Collector-emitter voltage		V _{CEO}	50	V
Emitter-base voltage		V_{EBO}	5	V
Collector current		I _{C(MAX.)} *1	100	mA
Collector Power dissipation EMH15 IMH15A		P _D *2	150 (Total) ^{*3}	mW
		P _D	300 (Total) ^{*4}	mW
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

●Electrical characteristics(Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV_CBO	I _C = 50μA	50	-	-	V
Collector-emitter breakdown voltage	BV_CEO	I _C = 1mA	50	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = 50μA	5	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 50V	-	-	0.5	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 4V	1	1	0.5	μΑ
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C / I_B = 5mA / 0.5mA$	ı	ı	0.3	V
DC current gain	h _{FE}	V_{CE} = 5V , I_{C} = 1mA	100	250	600	-
Input resistance	R ₁	-	32.9	47	61.1	kΩ
Transition frequency	f _T *1	$V_{CE} = 10V, I_{E} = -5mA,$ f = 100MHz	1	250	-	MHz

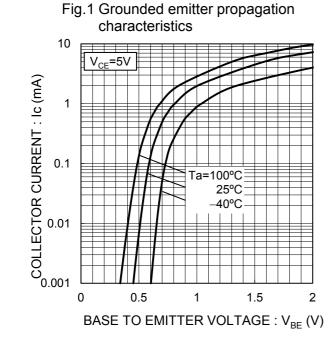
^{*1} Characteristics of built-in transistor

^{*2} Each terminal mounted on a reference footprint

^{*3 120}mW per element must not be exceeded.

^{*4 200}mW per element must not be exceeded.

●Electrical characteristic curves(Ta = 25°C)



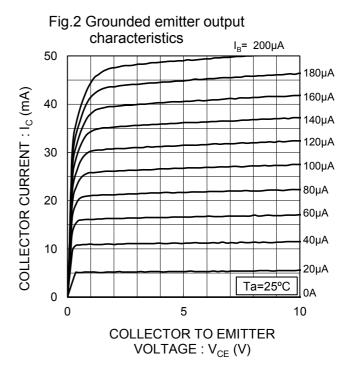
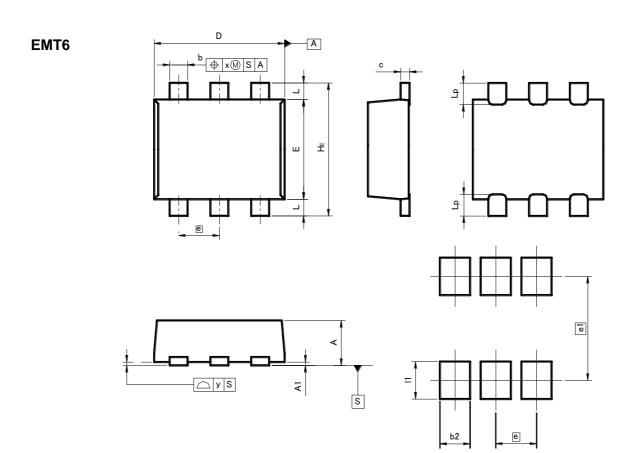


Fig.3 DC Current gain vs. Collector Current 1k V_{CE}=5V 500 DC CURRENT GAIN: hFE 200 100 Ta=100°C 25°C 50 -40°C 20 10 5 2 5m 10m 20m 50m 100m COLLECTOR CURRENT : I_C (mA)

vs. Collector Current $I_C/I_B=10$ 500m 200m **SOLLECTOR SATURATION** VOLTAGE: V_{CE}(sat) (V) Ta=100°C 100m 25°C 50m -40°C 20m 10m 5m 2m 1m 100μ 200μ 500μ 1m 2m 5m 10m 20m 50m100m COLLECTOR CURRENT : I_C (mA)

Fig.4 Collector-emitter saturation voltage

●Dimensions (Unit : mm)



Patterm of terminal position areas

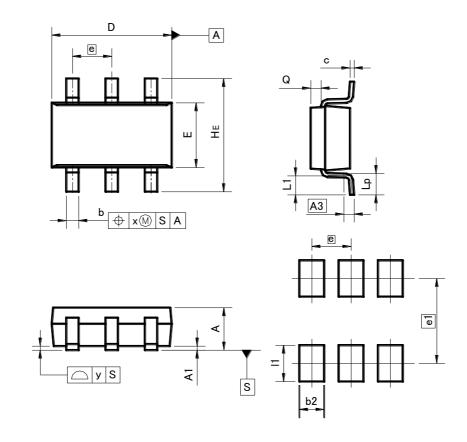
DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.10	0	0.004	
Α	0.45	0.55	0.018	0.022	
b	0.17	0.27	0.007	0.011	
С	0.08	0.18	0.003	0.007	
D	1.50	1.70	0.059	0.067	
Е	1.10	1.30	0.043	0.051	
е	0.	50	0.0	02	
HE	1.50	1.70	0.059	0.067	
L	0.10	0.30	0.004	0.012	
Lp	_	0.35	_	0.014	
х	_	0.10	-	0.004	
У	_	0.10	_	0.004	

DIM	MILIMI	ETERS	INCHES		
DIN	MIN MAX		MIN	MAX	
e1	1.25		0.049		
b2	-	- 0.37		0.015	
l1	- 0.45		_	0.018	

Dimension in mm/inches

●Dimensions (Unit : mm)

SMT6



Patterm of terminal position areas

DIM	MILIMI	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.00	1.30	0.039	0.051	
A1	0.00	0.10	0	0.004	
A3	0.2	25	0.0	01	
b	0.25	0.40	0.01	0.016	
С	0.09	0.25	0.004	0.01	
D	2.80	3.00	0.11	0.118	
E	1.50	1.80	0.059	0.071	
е	0.95		0.04		
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.20	0.30	0.008	0.012	
х		0.20	_	0.008	
У	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES	
DIM	MIN MAX		MIN	MAX
e1	2.10		0.08	
b2	0.60		ı	0.024
11	_	0.90	-	0.035

Dimension in mm/inches

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